

Table 3-3 Manufacturer's data sheet for a typical CMOS device,
the 54/74HC00 quad NAND gate.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE							
The following conditions apply unless otherwise specified: Commercial: $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$, $V_{CC} = 5.0\text{V}\pm 5\%$; Military: $T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{CC} = 5.0\text{V}\pm 10\%$							
Sym.	Parameter	Test Conditions⁽¹⁾		Min.	Typ.⁽²⁾	Max.	Unit
V_{IH}	Input HIGH level	Guaranteed logic HIGH level		3.15	—	—	V
V_{IL}	Input LOW level	Guaranteed logic LOW level		—	—	1.35	V
I_{IH}	Input HIGH current	$V_{CC} = \text{Max.}$, $V_I = V_{CC}$		—	—	1	μA
I_{IL}	Input LOW current	$V_{CC} = \text{Max.}$, $V_I = 0\text{ V}$		—	—	-1	μA
V_{IK}	Clamp diode voltage	$V_{CC} = \text{Min.}$, $I_N = -18\text{ mA}$		—	-0.7	-1.2	V
I_{IOS}	Short-circuit current	$V_{CC} = \text{Max.}$, ⁽³⁾ $V_O = \text{GND}$		—	—	-35	mA
V_{OH}	Output HIGH voltage	$V_{CC} = \text{Min.}$, $V_{IN} = V_{IL}$	$I_{OH} = -20\text{ }\mu\text{A}$	4.4	4.499	—	V
			$I_{OH} = -4\text{ mA}$	3.84	4.3	—	V
V_{OL}	Output LOW voltage	$V_{CC} = \text{Min.}$, $V_{IN} = V_{IH}$	$I_{OL} = 20\text{ }\mu\text{A}$	—	.001	0.1	V
			$I_{OL} = 4\text{ mA}$	—	0.17	0.33	
I_{CC}	Quiescent power supply current	$V_{CC} = \text{Max.}$ $V_{IN} = \text{GND or } V_{CC}$, $I_O = 0$		—	2	10	μA

SWITCHING CHARACTERISTICS OVER OPERATING RANGE, $C_L = 50\text{ pF}$

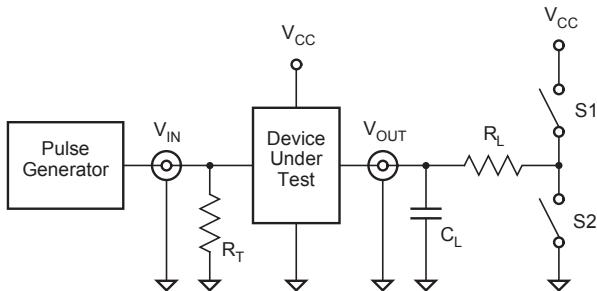
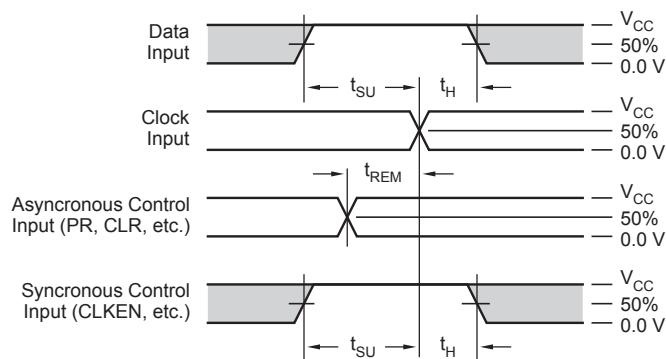
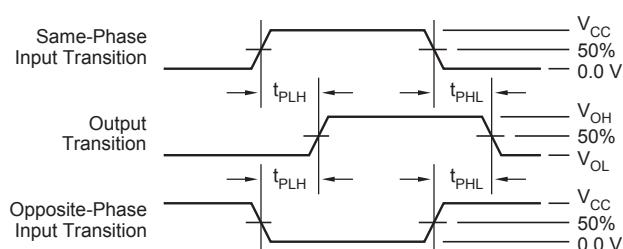
Sym.	Parameter⁽⁴⁾	Test Conditions	Min.	Typ.	Max.	Unit
t_{PD}	Propagation delay	A or B to Y	—	9	19	ns
C_I	Input capacitance	$V_{IN} = 0\text{ V}$	—	3	10	pF
C_{pd}	Power dissipation capacitance per gate	No load		—	22	—

NOTES:

- For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics.
- Typical values are at $V_{CC} = 5.0\text{ V}$, $+25^\circ\text{C}$ ambient.
- Not more than one output should be shorted at a time. Duration of short-circuit test should not exceed one second.
- This parameter is guaranteed but not tested.

WHAT'S IN A NUMBER?

Two different prefixes, “74” and “54,” are used in the part numbers of CMOS and TTL devices. These prefixes simply distinguish between commercial and military versions. A 74HC00 is the commercial part and the 54HC00 is the military version.

TEST CIRCUIT FOR ALL OUTPUTS**SETUP, HOLD, AND RELEASE TIMES****PROPAGATION DELAY****LOADING**

Parameter	R_L	C_L	S1	S2
t_{en}	1 k Ω	50 pF or 150 pF	Open	Closed
			Closed	Open
t_{dis}	1 k Ω		Open	Closed
			Closed	Open
t_{pd}	—	50 pF or 150 pF	Open	Open

DEFINITIONS:

C_L = Load capacitance, includes jig and probe capacitance.
 R_T = Termination resistance, should equal Z_{OUT} of the Pulse Generator.

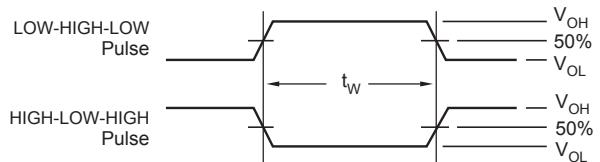
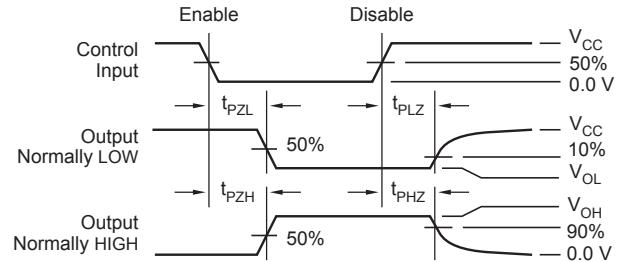
PULSE WIDTH**THREE-STATE ENABLE AND DISABLE TIMES**

Figure 3-24 Test circuits and waveforms for HC-series logic.

r
e
c
d

3
T
o
p

C